MSKSEMI美森科













ESD

TVS

TSS

MOV

GDT

PLED



Product specification





MS0402ESDA-XX

Other Data

Body	ZnO	
End termination	Ag/Ni/Sn	
Packaging	Таре	
Complies with Standard	IEC61000-4-2 、IEC61000-4-5	

Notes:

- *1 AC voltage at 50~60Hz
- *2 Varistor voltage
- *3 Capacitance
- *4 Maximum clamping voltage
- *5 Rated peak single pulsetransient current

Measured at 1mA DC Measured at f=1kHz,Vrms=0.5V Measured at 1A by 8/20µs Pulse Measured by 8/20µs Pulse

Technical Data	Symbol	Value	Unit
Maximum allowable continuous DC voltage	V _{DC}	5.0	V
Varistor voltage Measured*2 Varistor voltage tolerance	VB	130 ±20	V %
Typical capacitance value measured*3	С	1.0	pF
Typical capacitance value tolerance		±0.3	PF
Maximum clamping voltage measured*4	Vc	250	V

Reference Data

Response time	T _{rise}	<1	ns
Leakage current at $V_B \times 80\%$ (At initial state)	I _{LVB}	<20	μA
Leakage current at $V_B \times 80\%$ (After reliability Test)	Ilvba	<100	μA
Operating ambient temperature		55~+125	°C
Storage temperature		_ 40~+125	°C
Reflow temperature profile(Recommend)		260	°C



Size

				Unit: mm
PKG	Length (L)	Width (W)	High (H)	Termination (L1)
0402	1.00±0.20	0.50±0.20	0.70 (max)	0.30 ± 0.20





Ordering Information

P/N	PKG	QTY
MS0402ESDA-05	0402	10000
MS0402ESDA-09	0402	10000
MS0402ESDA-12	0402	10000
MS0402ESDA-14	0402	10000
MS0402ESDA-18	0402	10000
MS0402ESDA-24	0402	10000



V-I characteristic









Esd Wave Form



SEVERITY LEVEL	AIRDIRCHARGE	DIRECT ISCHARGE
1	2 kV	2 kV
2	4 kV	4 kV
3	8 kV	6 kV
4	15 kV	8 kV

IEC61000-4-2 Compliant ESD Current Pulse Waveform



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